

## ARTICLE

Systematic study of the UNiX<sub>2</sub> ternary compounds (X=C, Si, Ge)Kohei Ohashi<sup>a\*</sup>, Masaki Sawabu<sup>a</sup>, Kae Maeta<sup>a</sup>, Masashi Ohashi<sup>a</sup> and Tomoo Yamamura<sup>b</sup><sup>a</sup>Graduate School of Natural Science and Technology, Kanazawa University, Kakuma-cho, Kanazawa-shi, Ishikawa-ken, 920-1192, Japan; <sup>b</sup>Institute for Materials Research, Tohoku University, 2-1-1 Katahira, Aoba-ku, Sendai, Miyagi-ken, 980-8577, Japan

We attempted to grow UNiX<sub>2</sub> ternary compounds by the arc melting method. UNiC<sub>2</sub> and UNiGe<sub>2</sub> may not melt congruently because both compounds contain impurity phases. UNiC<sub>2</sub> crystallizes into the tetragonal UCoC<sub>2</sub>-type structure with space group *P4/nmm*, the annealed sample consists of UNiC<sub>2</sub> and U<sub>2</sub>NiC<sub>3</sub> as the main and secondary phases, respectively. The lattice constants were obtained to be  $a = 3.512 \text{ \AA}$ ,  $c = 7.339 \text{ \AA}$ . UNiGe<sub>2</sub> also contains two phases. We assumed that primary phase is isostructural to UNiSi<sub>2</sub> that crystallizes into the orthorhombic CeNiSi<sub>2</sub>-type structure with the space group of *Cmcm*. On the other hand, it is reasonable to assume that UNi<sub>2</sub>Ge<sub>2</sub> exists in the compound as secondary phase. The unit cell volume tends to increase as increasing the anomic number of X (C, Si, Ge). It comes from the fact that the atomic radius of X becomes larger as the atomic number becomes larger.

**Keywords:** uranium; nickel; ternary compounds; arc-melting method; X-ray powder diffraction

## 1. Introduction

Intermetallic compounds including Ce or U atoms have been investigated extensively because these compounds give important information for studying the role of strong electron correlations in metallic systems [1-4]. In these compounds, the ferromagnetic/antiferromagnetic interaction and Kondo effect compete with each other.

The ternary compounds CeTX<sub>2</sub> (T = transition metal and X = Si, Ge, Sn) form a large family having the orthorhombic CeNiSi<sub>2</sub>-type layered structure with space group *Cmcm*, and are constructed from deformed fragments of the CeGa<sub>2</sub>Al<sub>2</sub> and  $\alpha$ -ThSi<sub>2</sub> structures [5]. The lattice parameter along *b*-axis is extremely large compared to those along *a*- and *c*- axes, and the highly anisotropic magnetic property is expected. Indeed, these compounds have drawn considerable interest of a great variety of magnetic behaviors [6-8].

UNiSi<sub>2</sub> also crystallizes in orthorhombic CeNiSi<sub>2</sub>-type layered structure, and is a ferromagnet at  $T_C = 95 \text{ K}$  [9, 10]. Single crystals can be grown by Czochralski pulling method because UNiSi<sub>2</sub> melts congruently. The large anisotropic behavior is observed in the measurement of the magnetization of UNiSi<sub>2</sub> single crystal in the low-temperature ferromagnetic phase. The easy magnetization direction is in the *ac* plane. From the result of the magnetic susceptibility along the *ac* plane, the effective magnetic moment is obtained to be  $\mu_{\text{eff}} \sim 2.47\mu_B$  which is smaller than the value expected for the free U<sup>4+</sup> or U<sup>3+</sup> ions. It may come from highly

anisotropic magnetic property of UNiSi<sub>2</sub> [11].

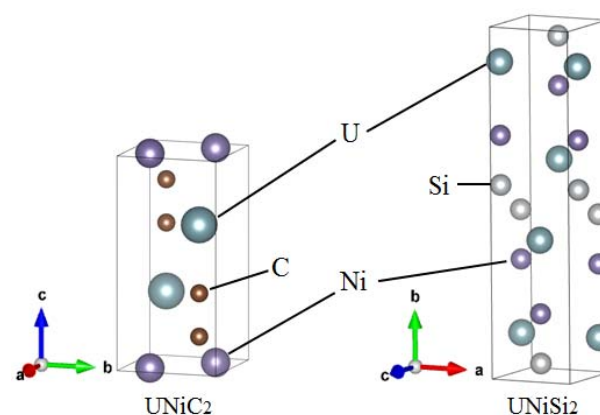


Figure 1. Crystal structure of UNiC<sub>2</sub> and UNiSi<sub>2</sub>.

On the other hand, there are few reports about UNiX<sub>2</sub> compounds except for UNiSi<sub>2</sub>. Gerss *et al.*, determined that UNiC<sub>2</sub> crystallizes into the tetragonal UCoC<sub>2</sub>-type structure with space group *P4/nmm* [12]. So, there may be much interest in the magnetic and electronic properties of UNiC<sub>2</sub> which is one of uranium compounds without a center of inversion. However, the physical properties of UNiC<sub>2</sub> such as magnetic susceptibility and heat capacity have not been reported yet. Recently Molčanová *et al.* synthesized UNiGe<sub>2</sub> by splat cooling, but the crystal structure has been unknown yet [13]. As for UNiSn<sub>2</sub>, there have not been reported at all. In the present work, we report on the synthesis of a ternary uranium compound UNiX<sub>2</sub>.

\*Corresponding author. Email: k-ohashi@stu.kanazawa-u.ac.jp

## 2. Experimental details

Polycrystalline samples of  $\text{UNiX}_2$  ( $X=\text{C, Ge}$ ) were synthesized by arc melting with a stoichiometric composition in an Ar gas atmosphere. To improve homogeneity, the samples were turned over and re-melted several times. The samples were subsequently sealed in an evacuated quartz tube and annealed. The samples of  $\text{UNiC}_2$  and  $\text{UNiGe}_2$  were annealed at 1100 °C for 7 days and 840 °C for 7 days, respectively. The samples were characterized by X-ray powder diffraction experiments using a Rigaku MiniFlex II diffractometer with  $\text{Cu-K}\alpha$  radiation. The simulation of the powder diffraction pattern and the visualization of the crystal structure were carried out by the VESTA 3 program [14].

## 3. Results and discussion

### 3.1. $\text{UNiC}_2$

**Figure 2** shows the X-ray diffraction pattern of  $\text{UNiC}_2$  for as-grown sample and annealed one. Almost all Bragg peaks became sharp after annealing. We indexed the Bragg peaks as the tetragonal type structure. The lattice constants were obtained to be  $a = 3.512 \text{ \AA}$ ,  $c = 7.339 \text{ \AA}$ . These results are consistent with those of the previous report [12]. The result of the simulation also support that the main phase is the tetragonal  $\text{UCoC}_2$ -type structure with space group  $P4/nmm$ . On the other hand, small unknown peaks appear in the annealed sample and can be indexed as the X-ray diffraction pattern of  $\text{U}_2\text{NiC}_3$  [15]. In preliminary measurement of dc magnetic susceptibility of annealed sample, two magnetic phase transitions are observed at 57 K and 140 K for annealed sample.

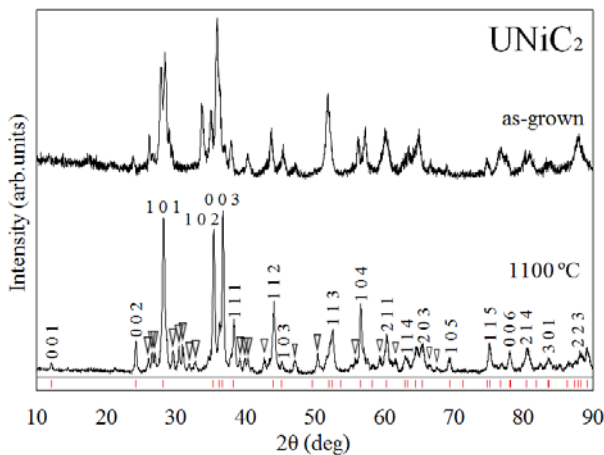


Figure 2. X-ray powder diffraction pattern of  $\text{UNiC}_2$ . Symbols ( $\nabla$ ) show unknown peaks. The ticks correspond to  $2\theta$  Bragg positions.

Taking account that  $\text{U}_2\text{NiC}_3$  is an antiferromagnet at  $T_N = 52 \text{ K}$  [16], the sample may consist of  $\text{UNiC}_2$  dominant phase of the tetragonal structure and  $\text{U}_2\text{NiC}_3$  secondary phase.

### 3.2. $\text{UNiGe}_2$

**Figure 3** shows the X-ray diffraction pattern of  $\text{UNiGe}_2$  for as-grown sample, and annealed one. Bragg peaks became sharp after annealing. Here we assumed that  $\text{UNiGe}_2$  has the same crystal structure as  $\text{UNiSi}_2$  and indexed the Bragg peaks as the orthorhombic  $\text{CeNiSi}_2$ -type structure with the space group of  $Cmcm$ . Because of the preferred orientation of powdered samples, the relative relations of peak-intensities between several Bragg peaks in the diffraction pattern are different from those in the simulation. But, as shown in Figure 3, almost all peaks correspond to  $2\theta$  Bragg positions calculated by the simulation. The lattice constants were obtained to be  $a = 3.993 \text{ \AA}$ ,  $b = 16.26 \text{ \AA}$ ,  $c = 4.094 \text{ \AA}$ . However, some peak expected to appear from the simulation are missing in the diffraction pattern. It may come from the fact that several Bragg peaks of the experimental result are hidden in the background.

On the other hand, Molčanová *et al.* also synthesized  $\text{UNiGe}_2$  by splat cooling. They found a new phase with some tetragonal structure [13]. It is unknown whether the new phase is same as the one we found because no experimental data has been described in their report.

Several unknown peaks are also observed in the X-ray diffraction pattern, and may correspond to the diffraction of  $\text{UNi}_2\text{Ge}_2$  as a secondary phase [17]. Similar behavior is also described in the recent report of Molčanová *et al.* [13]. Recently we report on the magnetic characterization of  $\text{UNiGe}_2$  and the magnetic susceptibility shows the large peak at 45 K and the small one at 65 K [18]. We associate the first transition with dominant magnetic phase of  $\text{UNiGe}_2$  while the second one may correspond to  $T_N$  of  $\text{UNi}_2\text{Ge}_2$  [17].

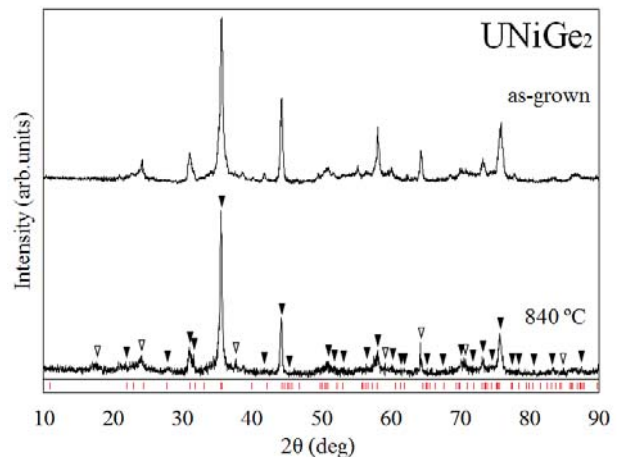


Figure 3. X-ray powder diffraction pattern of  $\text{UNiGe}_2$ . Symbols ( $\blacktriangledown$ ) and ( $\triangledown$ ) show  $\text{UNiGe}_2$  peaks and unknown peaks. The ticks correspond to  $2\theta$  Bragg positions.

## 4. Summary

Finally, we summarize the lattice parameters for the  $\text{UNiX}_2$  compounds in **Table 1**. The unit cell volume tends to increase as increasing the anomic number of X (C, Si, Ge). It comes from the fact that the atomic radius

of X becomes larger as the atomic number becomes larger. Although we tried to synthesize UNiSn<sub>2</sub> by arc melting, our result of the powder X-ray diffraction indicated the presence of UNi<sub>2</sub>Si<sub>2</sub> phase and U<sub>3</sub>Ni<sub>3</sub>Sn<sub>4</sub> one [19, 20].

UNiC<sub>2</sub> and UNiGe<sub>2</sub> may not melt congruently because both compounds contain two phases. Although we assumed that UNiGe<sub>2</sub> crystallizes into the orthorhombic structure in our preliminary study, it is needed to grow single crystal to verify our assumption. Further experiments are in progress to improve quality of samples and to investigate magnetic property.

Table 1. The lattice parameters for the UNiX<sub>2</sub> compounds.

	UNiC <sub>2</sub>	UNiSi <sub>2</sub> [11]	UNiGe <sub>2</sub>
<i>a</i> (Å)	3.512(1)	4.010	3.993(8)
<i>b</i> (Å)		16.10	16.26(6)
<i>c</i> (Å)	7.339(4)	4.009	4.094(3)
<i>V</i> (Å <sup>3</sup> )	90.5(1)	258.8	266(1)

### Acknowledgements

This work was performed under the inter-university cooperative research program of the cooperative research program of the Institute for Materials Research, Tohoku University (Proposal No. 17K0057). This work was supported in part by Futaba Electronics Memorial Foundation.

### References

- [1] Y. Uwatoko, I. Umehara, M. Ohashi, T. Nakano and G. Oomi, Chapter 252 - Thermal and Electronic Properties of Rare Earth Compounds at High Pressure, *Handbook on the Physics and Chemistry of Rare Earths*, 42 (2012), pp.1-164.
- [2] M. Ohashi, G. Oomi, S. Koiwai, M. Hedo and Y. Uwatoko, Fermi-liquid instability of CeRh<sub>2</sub>Si<sub>2</sub> near a pressure-induced quantum phase transition, *Phys. Rev. B* 68 (2003), 144428-1-7.
- [3] H. Miyagawa, G. Oomi, M. Ohashi, I. Satoh, T. Komatsubara, M. Hedo and Y. Uwatoko, Electronic states of single crystal CeAl<sub>2</sub> near the pressure-induced quantum critical point, *Phys. Rev. B* 78 (2008), 064403-1-8.
- [4] M. Ohashi, H. Miyagawa, T. Nakano, G. Oomi, V. Sechovsky, I. Satoh and T. Komatsubara, Thermal and Magnetic Properties in Ce<sub>1-x</sub>Er<sub>x</sub>Al<sub>2</sub> Intermetallic Compounds, *J. Phys. Soc. Jpn.* 83 (2014), 024701-1-5.
- [5] A. Iandelli and A. Palenzona, Chapter 13 Crystal chemistry of intermetallic compounds, 1979 *Handbook on the Physics and Chemistry of Rare Earths*, 2 (1979), pp.1-54.
- [6] M. Ohashi, G. Oomi, K. Ishida, I. Satoh, T. Komatsubara, T. Kawae and K. Takeda, Single-crystal growth of layered Ce-Ni-Ge ternary compounds, *J. Alloys and Compounds*, 84 (2006), pp.408-4012.
- [7] M. Ohashi, G. Oomi and I. Satoh, AC Magnetic Susceptibility Studies of Single Crystalline CeNiGe<sub>2</sub> under High Pressure, *J. Phys. Soc. Jpn.*, 76 (2007), 114712-1-3.
- [8] T. Nakano, M. Ohashi, G. Oomi, K. Matsubayashi and Y. Uwatoko, Pressure-induced superconductivity in the orthorhombic Kondo compound CePtSi<sub>2</sub>, *Phys. Rev. B* 79 (2009), 172507-1-4.
- [9] D. Kaczorowski, Magnetic behavior in UTSi<sub>2</sub> (T = Fe, Co and Ni) compounds, *Solid State Commun.* 99 (1996), pp.949-953.
- [10] T. Taniguchi, H. Morimoto, Y. Miyako and S. Ramakrishnan, Low-temperature specific heat of UNiSi<sub>2</sub>, *J. Magn. Magn. Mater.* 177-181 (1998), pp.55-56.
- [11] M. Ohashi, G. Oomi, K. Ishida and I. Satoh, Single crystal growth of RNiX<sub>2</sub> (R= U and Ce, X= Si and Ge) ternary compounds, *J. Phys. Soc. Jpn.* 75 (2006), pp.124-126.
- [12] M.H. Gerss and W. Jeitschko, The crystal structures of ternary actinoid iron (cobalt, nickel) carbides with composition 1:1:2, *Mat. Res. Bull.* 21 (1986), pp.209-216.
- [13] Z. Molčanová, M. Mihalik, M. Mihalik, Jr., M. Reiffers, A. Džubinská, M. Huráková, V. Kavečanský, M. Paukov and L. Havela, Characterization of New U-Ni-X<sub>2</sub> Splats and Study of their Physical Properties, *Acta Physica Polonica A*, 131 (2017), pp. 994-996.
- [14] K. Momma and F. Izumi, *VESTA 3* for three-dimensional visualization of crystal, volumetric and morphology data, *J. Appl. Crystallogr.* 44 (2011), pp.1272-1276.
- [15] M.H. Gerss and W. Jeitschko, The crystal structure of U<sub>2</sub>NiC<sub>3</sub>, *Zeitschrift für Kristallographie*. 175 (1986), pp.203-210.
- [16] T. Vomhof, R. Pöttgen and W. Jeitschko, Magnetic properties of the ternary uranium transition metal carbides UCrC<sub>2</sub>, UCr<sub>4</sub>C<sub>4</sub>, UW<sub>4</sub>C<sub>4</sub>, U<sub>5</sub>Re<sub>3</sub>C<sub>8</sub> and U<sub>2</sub>NiC<sub>3</sub>, *Journal of Alloys and Compounds*. 196 (1993), pp.173-176.
- [17] L. Ciehmicki, J. Leciejewicz and A. Zygmunt, Magnetic properties of UT<sub>2</sub>Si<sub>2</sub> and UT<sub>2</sub>Ge<sub>2</sub> (T = Co, Ni, Cu) intermetallic systems, *Journal of Physics and Chemistry of Solids*. 46 (1985), pp.529-538.
- [18] K. Ohashi, M. Ohashi, M. Sawabu, M. Miyagawa, K. Maeta and T. Yamamura, Magnetic properties of the UNiGe<sub>2</sub> at low temperature, accepted to *J. Phys. Conference Series*. (2017).
- [19] D. Kaczorowski, Z. Zolnierrek, C. Geibel and F. Steglich, Magnetic and electrical properties of (U, Th)T<sub>2</sub>Sn<sub>2</sub> (T ≡ Co, Ni, Cu) intermetallics, *Journal of Alloys and Compounds*. 200 (1993), pp.115-121.
- [20] M. Yethiraj, R.A. Robinson, J. Rhyne, J.A. Gotaas and K.H.J. Buschow, Magnetic and crystallographic properties of UNiSn, *Journal of Magnetism and Magnetic Materials*. 79 (1989), pp.355-357.